

## Dual N-Channel 190-V (D-S) MOSFET

PRODUCT SUMMARY			
$V_{DS}$ (V)	$R_{DS(on)}$ ( $\Omega$ )	$I_D$ (A) <sup>a</sup>	$Q_g$ (Typ.)
190	3.8 at $V_{GS} = 4.5$ V	0.95	1.4 nC
	4.2 at $V_{GS} = 2.5$ V	0.9	
	17 at $V_{GS} = 1.8$ V	0.3	

### FEATURES

- Halogen-free According to IEC 61249-2-21
- LITTLE FOOT<sup>®</sup> Power MOSFET
- New Thermally Enhanced PowerPAK<sup>®</sup> SC-70 Package
  - Small Footprint Area
  - Low On-Resistance
  - Thin 0.75 mm profile

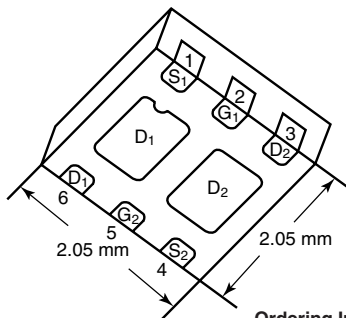


**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

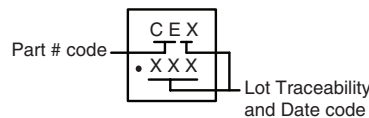
### APPLICATIONS

- DC/DC Converter for Portable Devices
- Load Switch for Portable Devices

PowerPAK SC-70-6 Dual

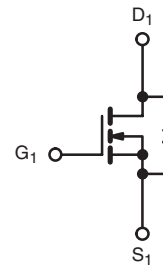


### Marking Code

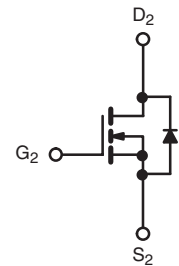


Lot Traceability and Date code

Ordering Information: SiA950DJ-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted			
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	190	V
Gate-Source Voltage	$V_{GS}$	$\pm 16$	
Continuous Drain Current ( $T_J = 150$ °C)	$I_D$	$T_C = 25$ °C	0.95
		$T_C = 70$ °C	0.76
		$T_A = 25$ °C	0.47 <sup>b, c</sup>
		$T_A = 70$ °C	0.38 <sup>b, c</sup>
Pulsed Drain Current	$I_{DM}$	1	A
Continuous Source-Drain Diode Current	$I_S$	$T_C = 25$ °C	
		$T_A = 25$ °C	0.47 <sup>b, c</sup>
Maximum Power Dissipation	$P_D$	$T_C = 25$ °C	7
		$T_C = 70$ °C	5
		$T_A = 25$ °C	1.9 <sup>b, c</sup>
		$T_A = 70$ °C	1.2 <sup>b, c</sup>
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	- 55 to 150	°C
Soldering Recommendations (Peak Temperature) <sup>d, e</sup>		260	

**THERMAL RESISTANCE RATINGS**

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>b, f</sup>	$t \leq 5$ s	$R_{thJA}$	52	65	°C/W
Maximum Junction-to-Case (Drain)	Steady State	$R_{thJC}$	12.5	16	

Notes:

a.  $T_C = 25$  °C.

b. Surface Mounted on 1" x 1" FR4 board.

c.  $t = 5$  s.d. See Solder Profile ([www.vishay.com/ppg?73257](http://www.vishay.com/ppg?73257)). The PowerPAK SC-70 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

e. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

f. Maximum under Steady State conditions is 110 °C/W.

**SPECIFICATIONS**  $T_J = 25$  °C, unless otherwise noted

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0$ V, $I_D = 250$ $\mu$ A	190			V
$V_{DS}$ Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = 250$ $\mu$ A		200		mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$		-3.0			
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250$ $\mu$ A	0.6		1.4	V
Gate-Source Leakage	$I_{GSS}$	$V_{DS} = 0$ V, $V_{GS} = \pm 16$ V			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 190$ V, $V_{GS} = 0$ V			1	$\mu$ A
		$V_{DS} = 190$ V, $V_{GS} = 0$ V, $T_J = 85$ °C			10	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \geq 5$ V, $V_{GS} = 4.5$ V	1			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = 4.5$ V, $I_D = 0.36$ A		3.0	3.8	$\Omega$
		$V_{GS} = 2.5$ V, $I_D = 0.35$ A		3.2	4.2	
		$V_{GS} = 1.8$ V, $I_D = 0.15$ A		3.5	17.0	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = 15$ V, $I_D = 0.36$ A		2		S
<b>Dynamic<sup>b</sup></b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 100$ V, $V_{GS} = 0$ V, $f = 1$ MHz		90		pF
Output Capacitance	$C_{oss}$		5			
Reverse Transfer Capacitance	$C_{rss}$		3			
Total Gate Charge	$Q_g$	$V_{DS} = 95$ V, $V_{GS} = 10$ V, $I_D = 0.47$ A		3	4.5	nC
		$V_{DS} = 95$ V, $V_{GS} = 4.5$ V, $I_D = 0.47$ A		1.4	2.1	
				0.25		
Gate-Source Charge	$Q_{gs}$		0.40			
Gate-Drain Charge	$Q_{gd}$					
Gate Resistance	$R_g$	$f = 1$ MHz		2.3		$\Omega$
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 95$ V, $R_L = 250$ $\Omega$ $I_D \cong 0.38$ A, $V_{GEN} = 4.5$ V, $R_g = 1$ $\Omega$		10	15	ns
Rise Time	$t_r$		15	25		
Turn-Off Delay Time	$t_{d(off)}$		25	40		
Fall Time	$t_f$		15	25		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 95$ V, $R_L = 250$ $\Omega$ $I_D \cong 0.38$ A, $V_{GEN} = 10$ V, $R_g = 1$ $\Omega$		3	10	ns
Rise Time	$t_r$		12	20		
Turn-Off Delay Time	$t_{d(off)}$		10	15		
Fall Time	$t_f$		10	15		
<b>Drain-Source Body Diode Characteristics</b>						
Continuous Source-Drain Diode Current	$I_S$	$T_C = 25$ °C			0.95	A
Pulse Diode Forward Current	$I_{SM}$				1	
Body Diode Voltage	$V_{SD}$	$I_S = 0.5$ A, $V_{GS} = 0$ V		0.8	1.2	V



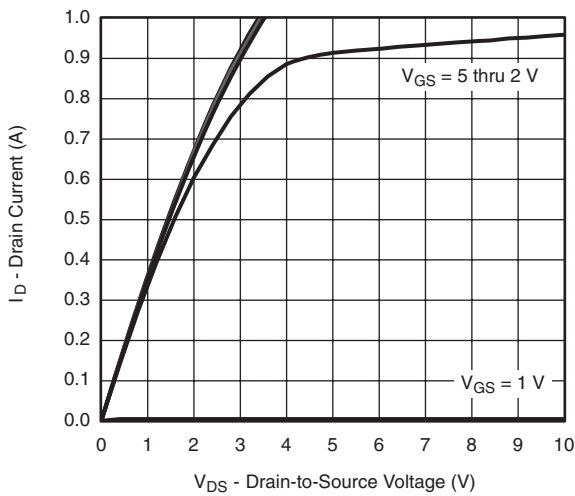
<b>SPECIFICATIONS</b> $T_J = 25\text{ }^\circ\text{C}$ , unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Drain-Source Body Diode Characteristics</b>						
Body Diode Reverse Recovery Time	$t_{rr}$	$I_F = 0.5\text{ A}$ , $di/dt = 100\text{ A}/\mu\text{s}$ , $T_J = 25\text{ }^\circ\text{C}$		45	70	ns
Body Diode Reverse Recovery Charge	$Q_{rr}$			45	70	nC
Reverse Recovery Fall Time	$t_a$			21		ns
Reverse Recovery Rise Time	$t_b$			24		

Notes:

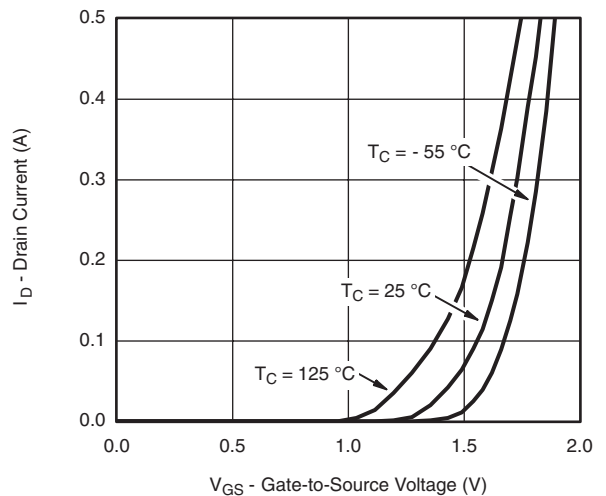
- a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

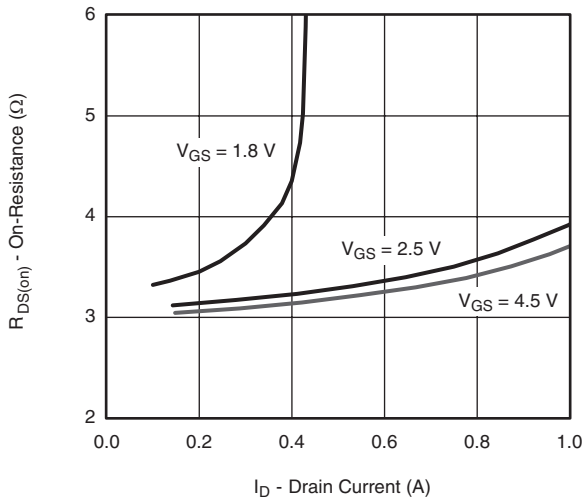
**TYPICAL CHARACTERISTICS**  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise noted



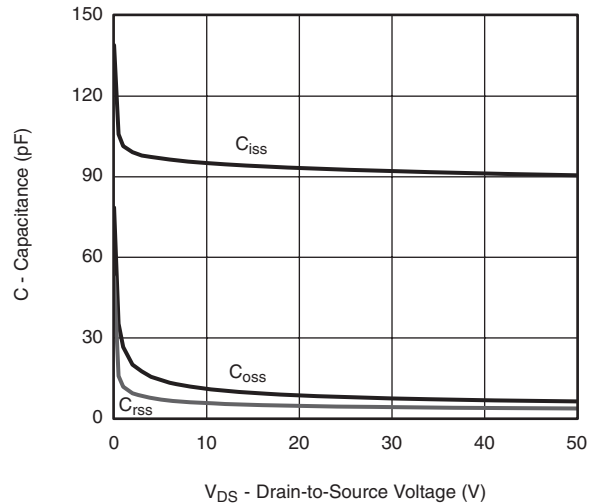
**Output Characteristics**



**Transfer Characteristics**

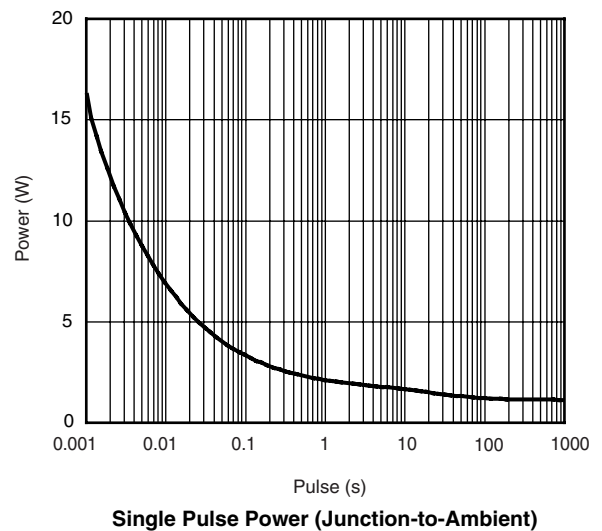
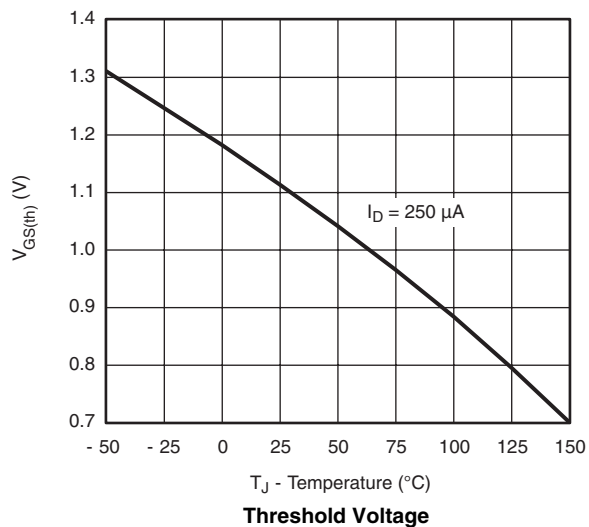
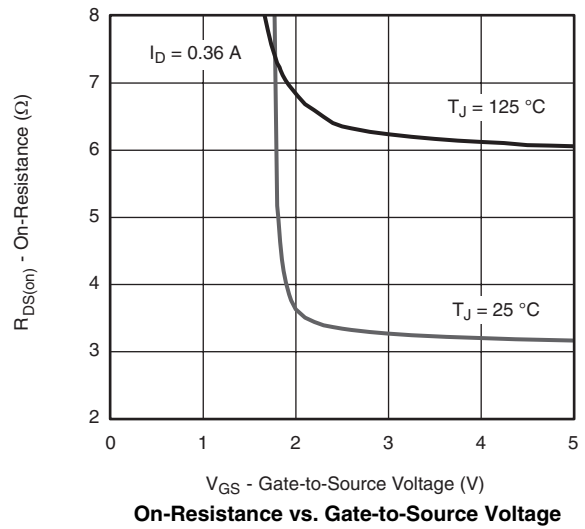
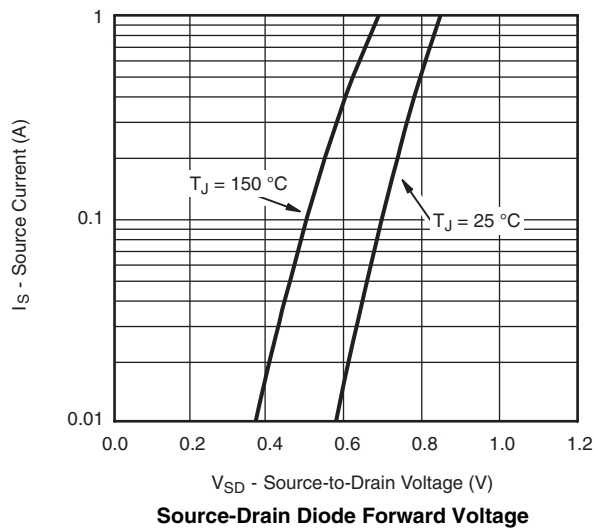
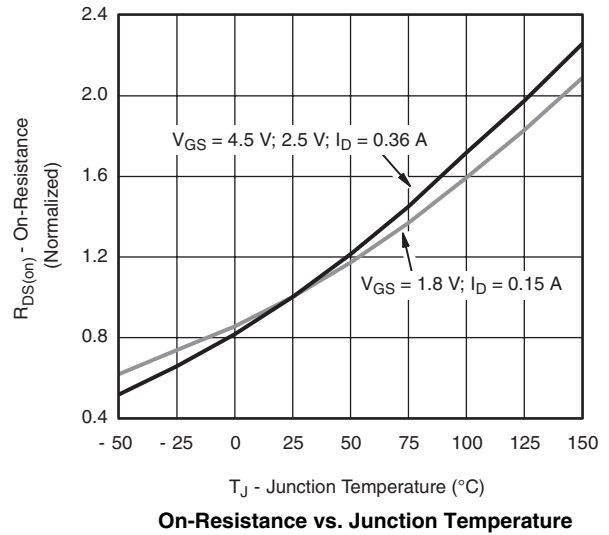
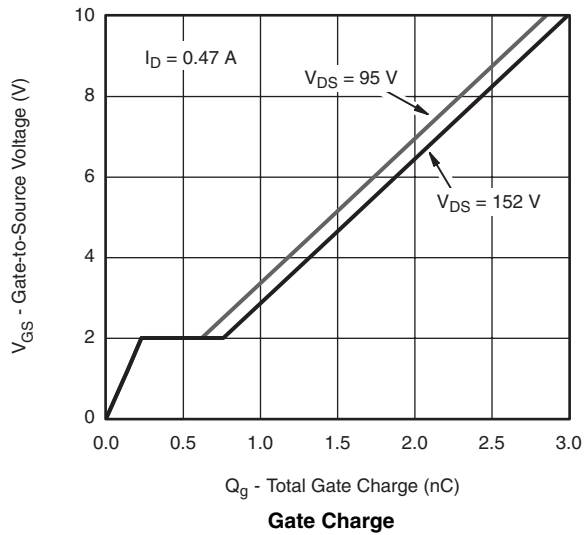


**On-Resistance vs. Drain Current**

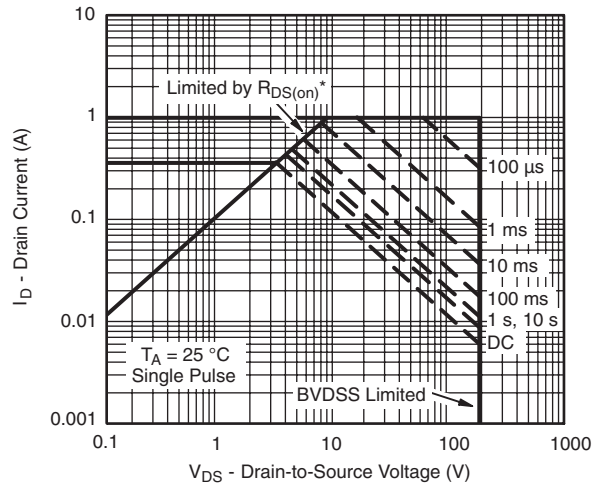


**Capacitance**

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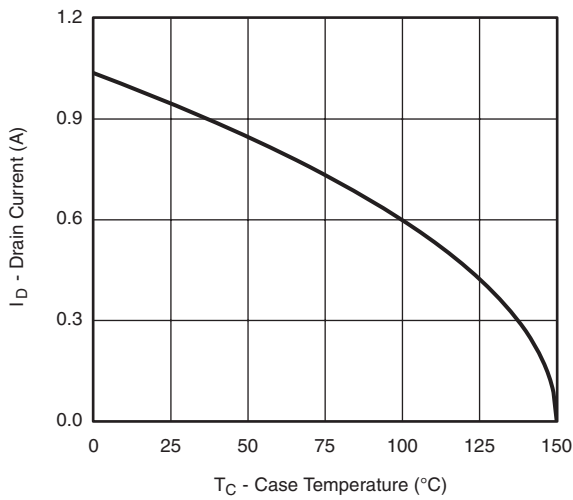


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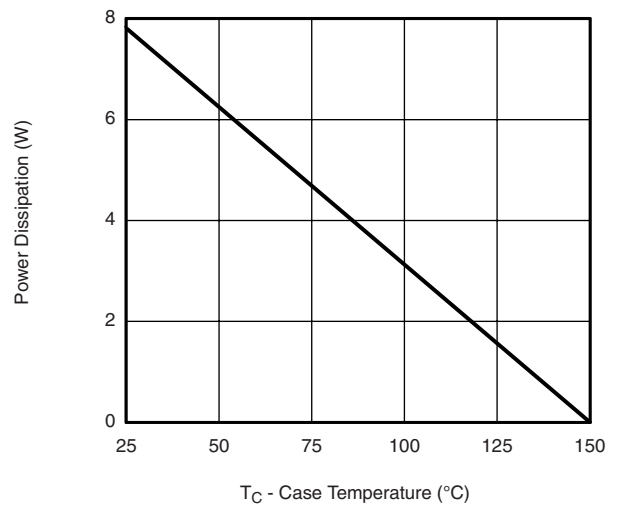


\*  $V_{GS} >$  minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

**Safe Operating Area, Junction-to-Ambient**



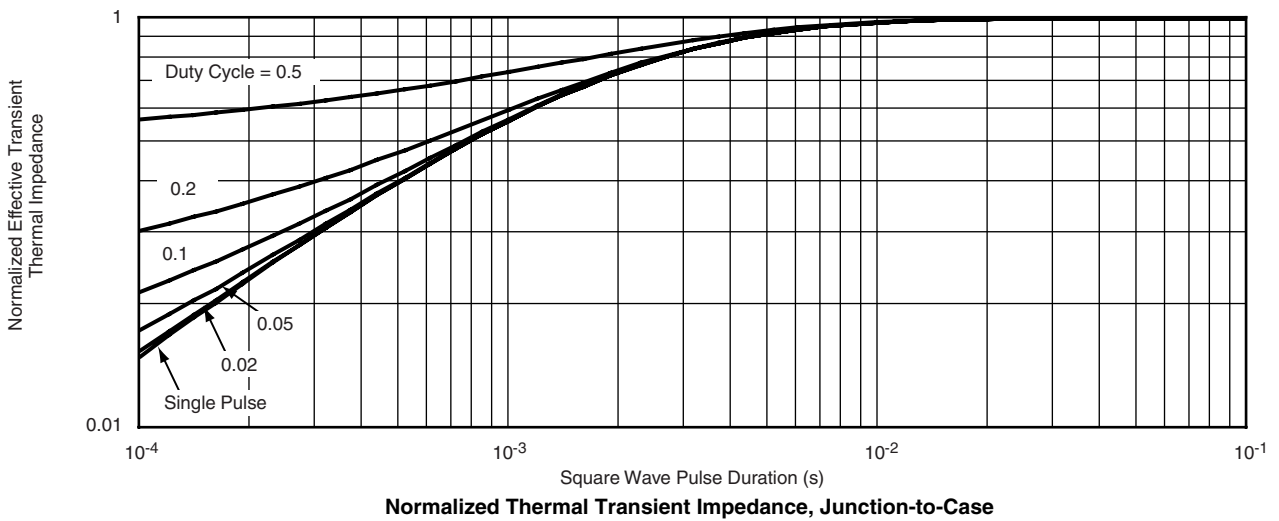
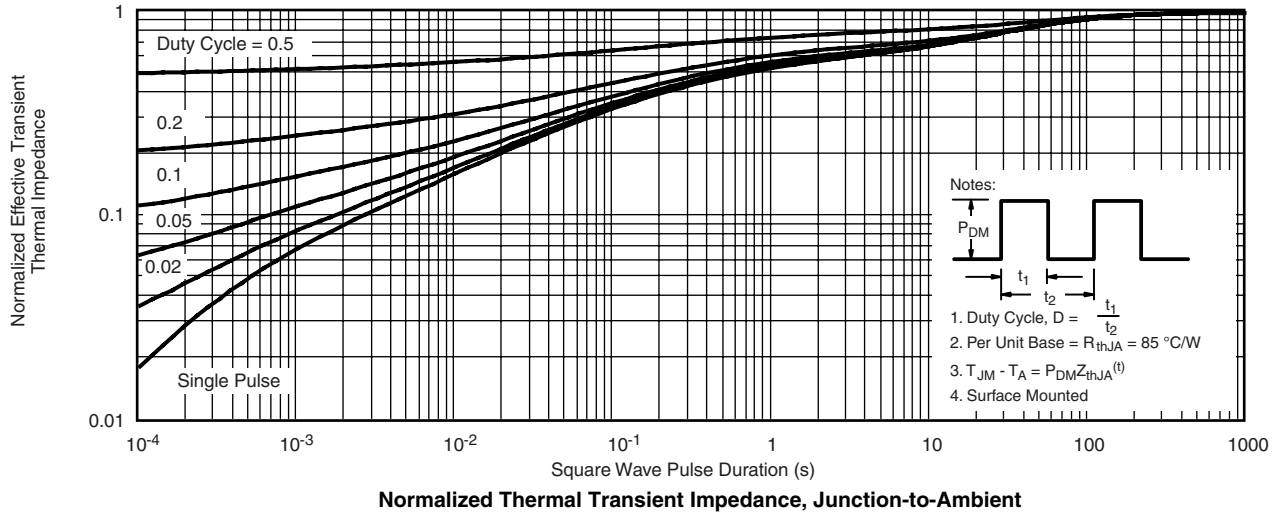
**Current Derating\***



**Power Derating**

\* The power dissipation  $P_D$  is based on  $T_{J(max)} = 150\text{ }^\circ\text{C}$ , using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

**TYPICAL CHARACTERISTICS**  $T_A = 25\text{ }^\circ\text{C}$ , unless otherwise noted



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